

Switching (600V, 7A)

2SK2740

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

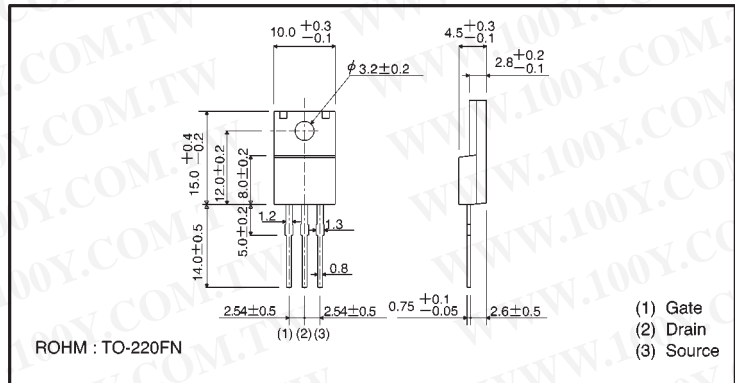
●Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Wide SOA (safe operating area).
- 4) Gate-source voltage (V_{GS}) guaranteed to be $\pm 30V$.
- 5) Easily designed drive circuits.
- 6) Easy to parallel.

●Structure

Silicon N-channel
 MOSFET

●External dimensions (Units: mm)



●Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit	
Drain-source voltage	V_{DS}	600	V	
Gate-source voltage	V_{GS}	± 30	V	
Drain current	Continuous	I_D	7	A
	Pulsed	I_{DP}^*	28	A
Reverse drain current	Continuous	I_{DR}	7	A
	Pulsed	I_{DRP}^*	28	A
Total power dissipation ($T_c=25^\circ\text{C}$)	P_D	30	W	
Channel temperature	T_{ch}	150	$^\circ\text{C}$	
Storage temperature	T_{stg}	$-55 \sim +150$	$^\circ\text{C}$	

* $P_W \leq 10 \mu\text{s}$, Duty cycle $\leq 1\%$

●Packaging specifications

Type	Package	Bulk
	Code	—
	Basic ordering unit (pieces)	500
2SK2740		○

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Gate-source leakage	I _{GSS}	—	—	±100	nA	V _{GS} =±30V, V _{DS} =0V
Drain-source breakdown voltage	V _{(BR)DSS}	600	—	—	V	I _D =1mA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}	—	—	100	μA	V _{DS} =600V, V _{GS} =0V
Gate threshold voltage	V _{GS(th)}	2.0	—	4.0	V	V _{DS} =10V, I _D =1mA
Static drain-source on-state resistance	R _{DS(on)}	—	1.0	1.2	Ω	I _D =4A, V _{GS} =10V
Forward transfer admittance	Y _{fs} *	3.0	6.0	—	S	I _D =4A, V _{DS} =10V
Input capacitance	C _{iss}	—	1050	—	pF	V _{DS} =10V
Output capacitance	C _{oss}	—	210	—	pF	V _{GS} =0V
Reverse transfer capacitance	C _{rss}	—	80	—	pF	f=1MHz
Turn-on delay time	t _{d(on)}	—	19	—	ns	I _D =4A, V _{DD} =150V
Rise time	t _r	—	22	—	ns	V _{GS} =10V
Turn-off delay time	t _{d(off)}	—	79	—	ns	R _L =37.5Ω
Fall time	t _f	—	30	—	ns	R _G =10Ω
Reverse recovery time	t _{rr}	—	590	—	ns	I _{DR} =7A, V _{GS} =0V
Reverse recovery charge	Q _{rr}	—	4.6	—	μC	di/dt=100A/μs

* Pw ≤ 300 μs, Duty cycle ≤ 1%

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●Electrical characteristic curves

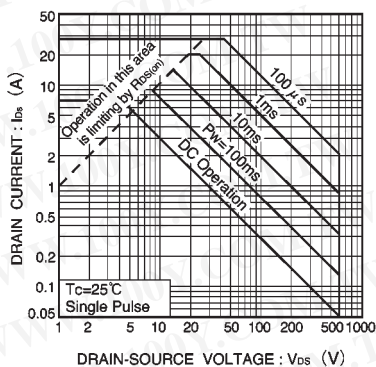


Fig.1 Maximum safe operating area

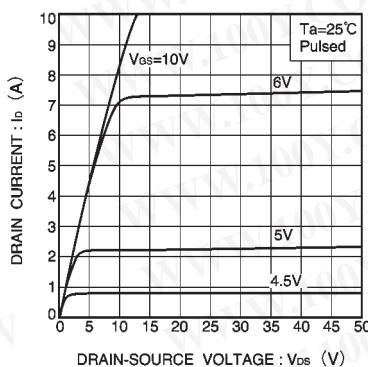


Fig.2 Typical output characteristics

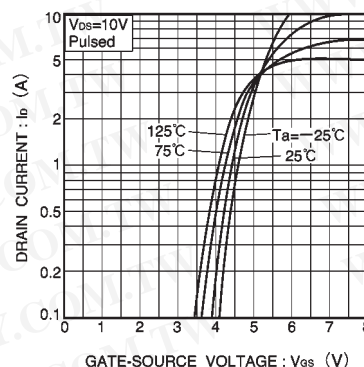


Fig.3 Typical transfer characteristics

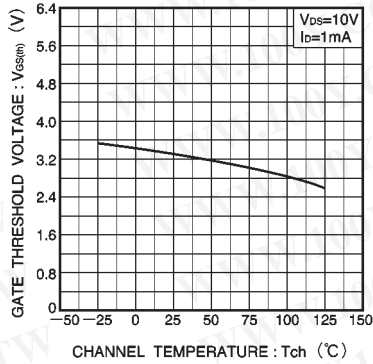


Fig.4 Gate threshold voltage vs. channel temperature

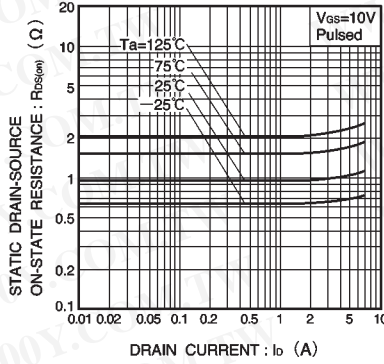


Fig.5 Static drain-source on-state resistance vs. drain current

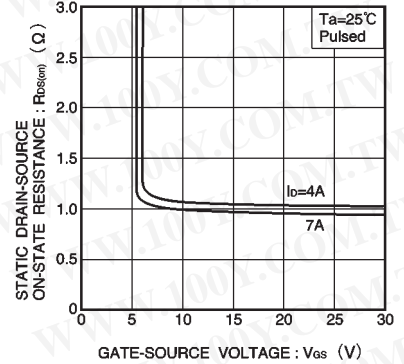


Fig.6 Static drain-source on-state resistance vs. gate-source voltage

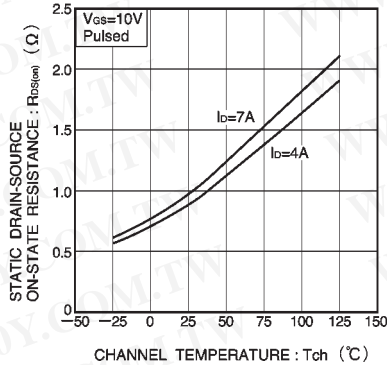


Fig.7 Static drain-source on-state resistance vs. channel temperature

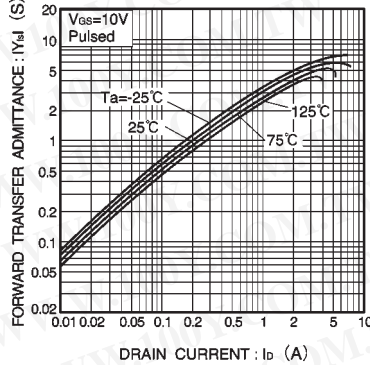


Fig.8 Forward transfer admittance vs. drain current

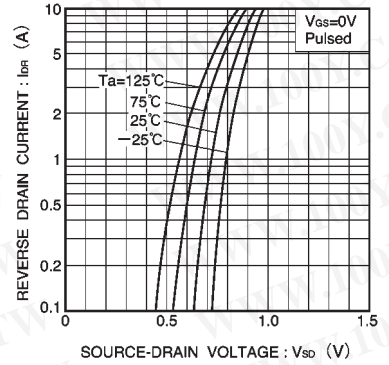


Fig.9 Reverse drain current vs. source-drain voltage (I)

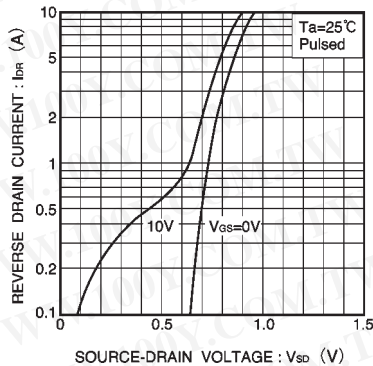


Fig.10 Reverse drain current vs. source-drain voltage (II)

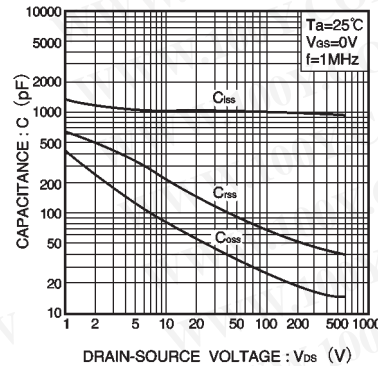


Fig.11 Typical capacitance vs. drain-source voltage

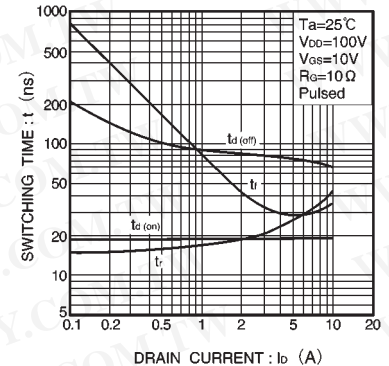


Fig.12 Switching characteristics (See Figures 16 and 17 for the measurement circuit and resultant waveforms)

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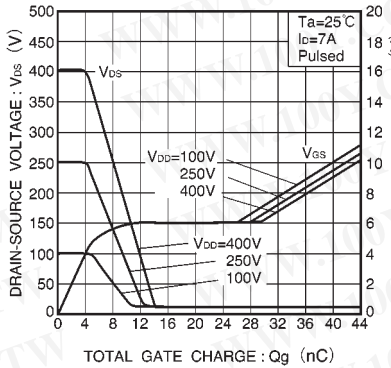


Fig.13 Dynamic input characteristics
 (See Figure 18 for measurement circuit)

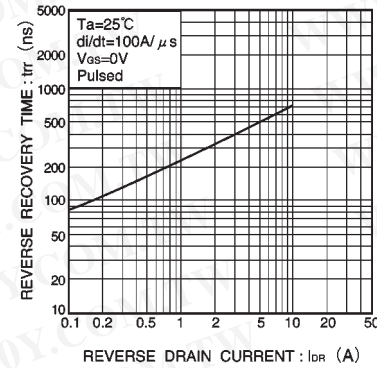


Fig.14 Reverse recovery time vs. reverse drain current

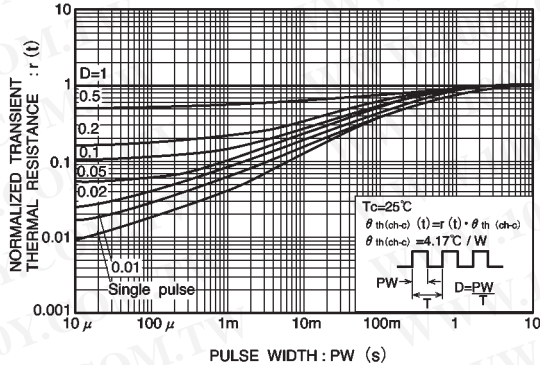


Fig.15 Normalized transient thermal resistance vs. pulse width

● Switching characteristics measurement circuit

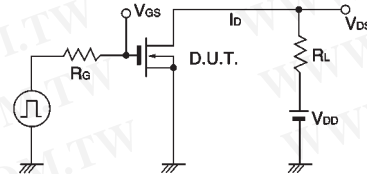


Fig.16 Switching time measurement circuit

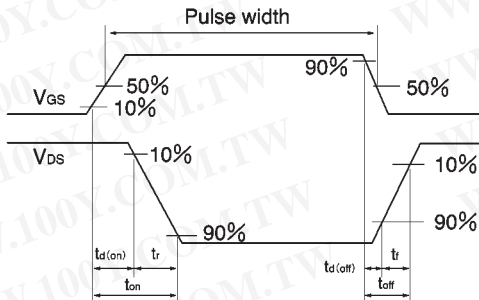


Fig.17 Switching time waveforms

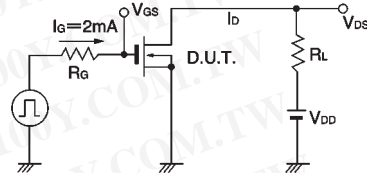


Fig.18 Gate charge measurement circuit

Appendix

Notes

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